



US2ABF THRU US2MBF

SURFACE MOUNT ULTRA FAST RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 2.0 Amperes

FEATURES

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Ultra fast switching for high efficiency
- Low reverse leakage
- Built-in strain relief, ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed
- 260 C/10 seconds at terminals
- Glass passivated chip junction

MECHANICAL DATA

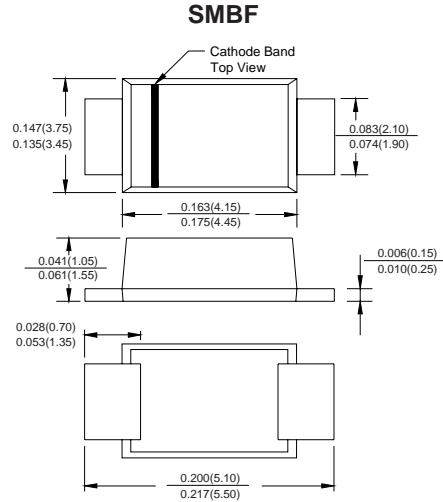
Case: JEDEC SMBF molded plastic body over passivated chip

Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.002 ounce, 0.056 grams



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

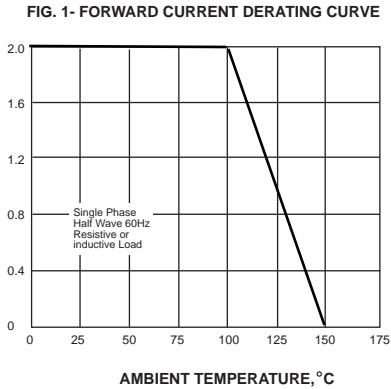
	SYMBOLS	US2ABF	US2BBF	US2DBF	US2GBF	US2JBF	US2KBF	US2MBF	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current at $T_L=100^\circ\text{C}$	$I_{(AV)}$	2.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50.0							Amps
Maximum instantaneous forward voltage at 2.0A	V_F	1.0		1.4	1.7			Volts	
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	I_R	5.0 100.0							μA
Maximum reverse recovery time (NOTE 1)	t_{rr}	50				75			ns
Typical junction capacitance (NOTE 2)	C_J	50.0							pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	75.0							$^\circ\text{C/W}$
Operating junction and storage temperature range	T_J, T_{STG}	-55 to +150							$^\circ\text{C}$

- Note:**
- 1.Reverse recovery condition $I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$
 - 2.Measured at 1MHz and applied reverse voltage of 4.0V D.C.
 - 3.P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad area

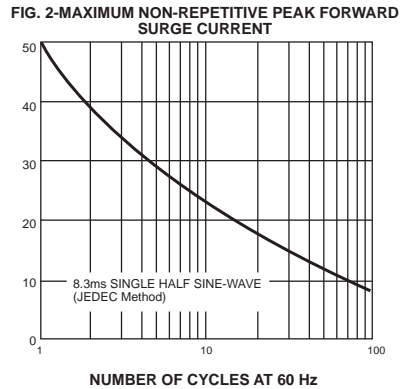


RATINGS AND CHARACTERISTIC CURVES US2ABF THRU US2MBF

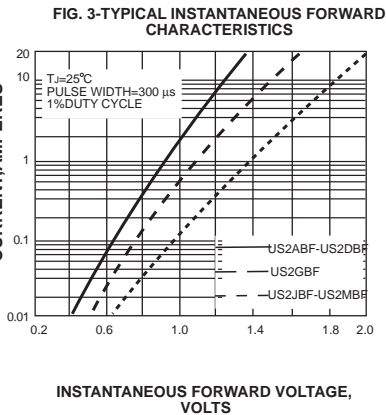
AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES



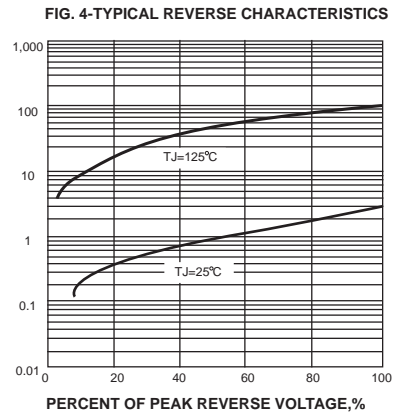
PEAK FORWARD SURGE CURRENT
AMPERES



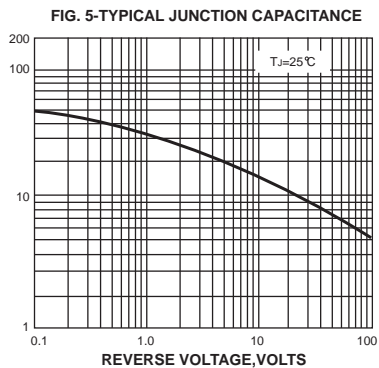
INSTANTANEOUS FORWARD CURRENT, AMPERES



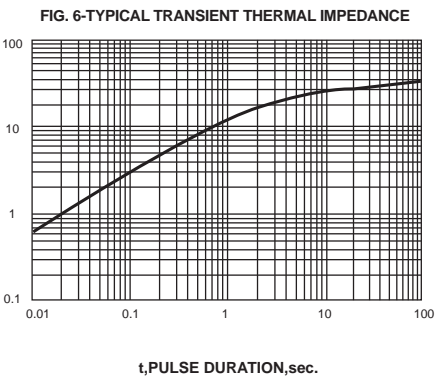
INSTANTANEOUS REVERSE CURRENT,
MICROAMPERES



JUNCTION CAPACITANCE, pF



TRANSIENT THERMAL IMPEDANCE,
°C/W



t, PULSE DURATION, sec.